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- *EPIC* [™] (Enhanced-Performance Implanted CMOS) 1-μm Process
- Package Options Include Plastic Small-Outline (D), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Standard Plastic (N) and Ceramic (J) DIPS

description

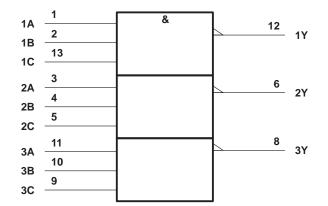
The 'AC11 contain three independent 3-input AND gates. These devices perform the Boolean function $Y = A \cdot B \cdot C$ or $Y = \overline{A + B} + \overline{C}$ in positive logic.

The SN54AC11 is characterized for operation over the full military temperature range of -55° C to 125° C. The SN74AC11 is characterized for operation from -40° C to 85° C.

FUN	ICTIC)N (TAB	LE
(each	ga	te)	

	INPUTS		OUTPUT
Α	В	С	Y
Н	Н	Н	Н
L	Х	Х	L
Х	L	Х	L
Х	Х	L	L

logic symbol[†]



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the D, DB, J, N, PW, and W packages.



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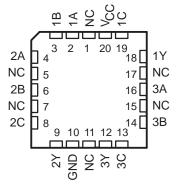
PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



SN74AC11 D, DB, N, OR PW PACKAGE (TOP VIEW)									
1A [1	14	V _{CC}						
1B [2	13	1C						
2A [3	12	1Y						
2B [4	11	3A						
2C [5	10	3B						
2Y [6	9	3C						
GND [7	8	3Y						

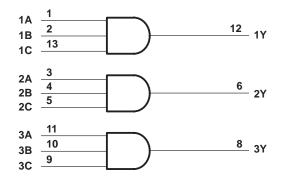
SN54AC11 ... J OR W PACKAGE

SN54AC11 ... FK PACKAGE (TOP VIEW)



NC - No internal connection

logic diagram, each gate (positive logic)



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

N P\	$\begin{array}{cccc} -0.5 \mbox{ V to } \mbox{V}_{CC} + 0.5 \mbox{ V} \\ -0.5 \mbox{ V to } \mbox{V}_{CC} + 0.5 \mbox{ V} \\ \pm 20 \mbox{ mA} \\ \pm 20 \mbox{ mA} \\ \pm 50 \mbox{ mA} \\ \pm 200 \mbox{ mA} \\ \pm 200 \mbox{ mA} \\ \mbox{ max} \\ $
Storage temperature range, T _{stg}	–65°C to 150°C

⁺ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils, except for the N package, which has a trace length of zero.

recommended operating conditions (see Note 3)

			SN54/	SN54AC11		SN74AC11	
			MIN	MAX	MIN	MAX	UNIT
V _{CC}	Supply voltage		2	6	2	6	V
		$V_{CC} = 3 V$	2.1		2.1		
VIH	High-level input voltage	$V_{CC} = 4.5 V$	3.15		3.15		V
		V _{CC} = 5.5 V	3.85		3.85		
		$V_{CC} = 3 V$		0.9		0.9	
VIL	Low-level input voltage	$V_{CC} = 4.5 V$		1.35		1.35	V
		$V_{CC} = 5.5 V$		1.65		1.65	
VI	Input voltage		0	VCC	0	VCC	V
VO	Output voltage		0	VCC	0	VCC	V
		$V_{CC} = 3 V$		-12		-12	
IOH	High-level output current	$V_{CC} = 4.5 V$		-24		-24	mA
		$V_{CC} = 5.5 V$		-24		-24	
		$V_{CC} = 3 V$		12		12	
IOL	Low-level output current	$V_{CC} = 4.5 V$		24		24	mA
		V _{CC} = 5.5 V		24		24	
$\Delta t / \Delta v$	Input transition rise or fall rate		0	8	0	8	ns/V
TA	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.



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PARAMETER	TEST CONDITIONS	N	Т	T _A = 25°C		SN54	AC11	SN74/	AC11	UNIT
PARAMETER	TEST CONDITIONS	v _{cc}		TYP	MAX	MIN	MAX	MIN	MAX	UNIT
		3 V	2.9	2.99		2.9		2.9		
	I _{OH} = - 50 μA	4.5 V	4.4	4.49		4.4		4.4		
		5.5 V	5.4	5.49		5.4		5.4		
Vau	I _{OH} = – 12 mA	3 V	2.56			2.4		2.46		V
Voh		4.5 V	3.86			3.7		3.76		v
	I _{OH} = - 24 mA	5.5 V	4.86			4.7		4.76		
	I _{OH} = - 50 mA [†]	5.5 V				3.85				
	$I_{OH} = -75 \text{ mA}^{\dagger}$	5.5 V						3.85		
		3 V		0.002	0.1		0.1		0.1	
	I _{OL} = 50 μA	4.5 V		0.001	0.1		0.1		0.1	
		5.5 V		0.001	0.1		0.1		0.1	
Vo	I _{OL} = 12 mA	3 V			0.36		0.5		0.44	V
VOL	I _{OL} = 24 mA	4.5 V			0.36		0.5		0.44	v
	-	5.5 V			0.36		0.5		0.44	
	$I_{OL} = 50 \text{ mA}^{\dagger}$	5.5 V					1.65			
	$I_{OL} = 75 \text{ mA}^{\dagger}$	5.5 V							1.65	
l	$V_{I} = V_{CC}$ or GND	5.5 V			±0.1		±1		±1	μΑ
lCC	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	5.5 V			2		40		20	μΑ
Ci	$VI = V_{CC} \text{ or } GND$	5 V		2.6						pF

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

[†]Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	Т,	Δ = 25°C	;	SN54	AC11	SN74	AC11	UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
^t PLH	Any	V	1.5	5.5	9.5	1	11	1	10	
^t PHL		T	1.5	5.5	8.5	1	10.5	1	9.5	ns

switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

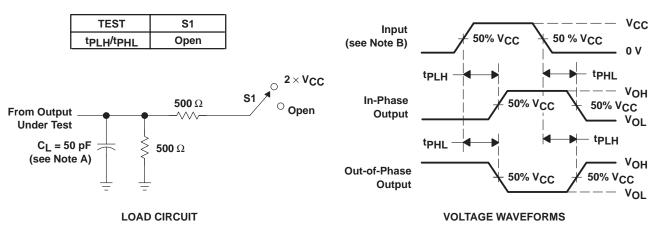
ſ	PARAMETER FROM	то	Т,	₄ = 25°C	;	SN54	AC11	SN74	AC11	UNIT	
	FARAMETER	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
	^t PLH	Any	v v	1.5	4	8	1	8.5	1	8.5	ns
	^t PHL			1.5	4	7	1	8	1	7.5	115

operating characteristics, V_{CC} = 5 V, T_A = 25° C

PARAMETER	TEST CONDITIONS	ТҮР	UNIT
C _{pd} Power dissipation capacitance	$C_L = 50 \text{ pF}, \text{ f} = 1 \text{ MHz}$	20	pF



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PARAMETER MEASUREMENT INFORMATION

NOTES: A. CL includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r \leq 2.5 ns, t_f \leq 2.5 ns.
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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